## **DISCRETE SEMICONDUCTORS**

# DATA SHEET

# **PDTA144W series** PNP resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = 22 k $\Omega$

Product data sheet Supersedes data of 2004 Mar 23 2004 Aug 05



# PNP resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = 22 k $\Omega$

## PDTA144W series

#### **FEATURES**

- Built-in bias resistors
- Simplified circuit design
- Reduction of component count
- · Reduced pick and place costs.

### **APPLICATIONS**

- General purpose switching and amplification
- · Inverter and interface circuits
- Circuit driver.

#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	TYP.	MAX.	UNIT
$V_{CEO}$	collector-emitter voltage	_	-50	V
Io	output current (DC)	_	-100	mA
R1	bias resistor	47	_	kΩ
R2	bias resistor	22	_	kΩ

### **DESCRIPTION**

PNP resistor-equipped transistor (see "Simplified outline, symbol and pinning" for package details).

#### **PRODUCT OVERVIEW**

TVDE NUMBER	PAC	KAGE	MARKING CORE	NDN COMPLEMENT
TYPE NUMBER	PHILIPS	EIAJ	MARKING CODE	NPN COMPLEMENT
PDTA144WE	SOT416	SC-75	5D	PDTC144WE
PDTA144WEF	SOT490	SC-89	2E	PDTC144WEF
PDTA144WK	SOT346	SC-59	46	PDTC144WK
PDTA144WM	SOT883	SC-101	F8	PDTC144WM
PDTA144WS	SOT54 (TO-92)	SC-43	TA144W	PDTC144WS
PDTA144WT	SOT23	_	*43 <sup>(1)</sup>	PDTC144WT
PDTA144WU	SOT323	SC-70	*28 <sup>(1)</sup>	PDTC144WU

### Note

<sup>1. \* =</sup> p: Made in Hong Kong.

<sup>\* =</sup> t: Made in Malaysia.

<sup>\* =</sup> W: Made in China.

# PNP resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = 22 k $\Omega$

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# SIMPLIFIED OUTLINE, SYMBOL AND PINNING

TYPE NUMBER	CIMPLIFIED OUTLINE AND CYMPOL	PINNING		
TYPE NUMBER	SIMPLIFIED OUTLINE AND SYMBOL	PIN	DESCRIPTION	
PDTA144WS	1 R1 R2 3 MAM338	1 2 3	base collector emitter	
PDTA144WE PDTA144WEF PDTA144WK PDTA144WT PDTA144WU	3 1 R1 R2 Top view MDB271	1 2 3	base emitter collector	
PDTA144WM	2 R1 3 R2 R2 MDB267	1 2 3	base emitter collector	

## PNP resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = 22 k $\Omega$

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### **ORDERING INFORMATION**

TYPE NUMBER	PACKAGE						
ITPE NUMBER	NAME	DESCRIPTION	VERSION				
PDTA144WE	_	plastic surface mounted package; 3 leads	SOT416				
PDTA144WEF – plast		plastic surface mounted package; 3 leads	SOT490				
PDTA144WK –		plastic surface mounted package; 3 leads	SOT346				
PDTA144WM –		leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.5 mm	SOT883				
PDTA144WS	_	plastic single-ended leaded (through hole) package; 3 leads	SOT54				
PDTA144WT –		plastic surface mounted package; 3 leads	SOT23				
PDTA144WU	_	plastic surface mounted package; 3 leads	SOT323				

### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	_	-50	V
V <sub>CEO</sub>	collector-emitter voltage	open base	_	-50	V
V <sub>EBO</sub>	emitter-base voltage	open collector	_	-10	V
VI	input voltage				
	positive		_	+10	V
	negative		_	-40	V
Io	output current (DC)		_	-100	mA
I <sub>CM</sub>	peak collector current		_	-100	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C;$			
	SOT54	note 1	_	500	mW
	SOT23	note 1	_	250	mW
	SOT346	note 1	_	250	mW
	SOT323	note 1	_	200	mW
	SOT416	note 1	_	150	mW
	SOT490	notes 1 and 2	_	250	mW
	SOT883	notes 2 and 3	_	250	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C

### **Notes**

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60  $\mu m$  copper strip line.

# PNP resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = 22 k $\Omega$

## PDTA144W series

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	T <sub>amb</sub> ≤ 25 °C		
	SOT54	note 1	250	K/W
	SOT23	note 1	500	K/W
	SOT346	note 1	500	K/W
	SOT323	note 1	625	K/W
	SOT416	note 1	830	K/W
	SOT490	notes 1 and 2	500	K/W
	SOT883	notes 2 and 3	500	K/W

## Note

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions.; FR4 with 60  $\mu m$  copper strip line.

### **CHARACTERISTICS**

 $T_{amb}$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	PARAMETER CONDITIONS		TYP.	MAX.	UNIT
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = -50 \text{ V}; I_E = 0 \text{ A}$	_	_	-100	nA
I <sub>CEO</sub>	collector-emitter cut-off current	$V_{CE} = -30 \text{ V}; I_B = 0 \text{ A}$	_	_	-1	μΑ
		$V_{CE} = -30 \text{ V}; I_{B} = 0 \text{ A}; T_{j} = 150 ^{\circ}\text{C}$	_	_	-50	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_{C} = 0 \text{ A}$	_	_	-110	μΑ
h <sub>FE</sub>	DC current gain	$V_{CE} = -5 \text{ V}; I_{C} = -5 \text{ mA}$	60	_	_	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = -10 \text{ mA}; I_B = -0.5 \text{ mA}$	_	_	-150	mV
$V_{i(off)}$	input-off voltage	$I_C = -100 \mu A; V_{CE} = -5 V$	_	-1.7	-1.2	V
$V_{i(on)}$	input-on voltage	$I_C = -2 \text{ mA}; V_{CE} = -0.3 \text{ V}$	-4	-2.7	_	V
R1	input resistor		33	47	61	kΩ
R2 R1	resistor ratio		0.37	0.47	0.57	
C <sub>c</sub>	collector capacitance	$I_E = I_e = 0 \text{ A}; V_{CB} = -10 \text{ V};$ f = 1 MHz	_	_	3	pF

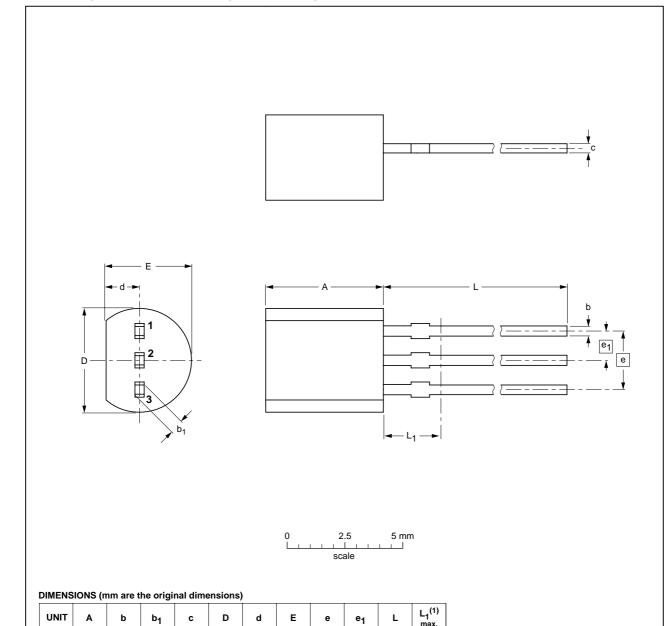
# PNP resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = 22 k $\Omega$

## PDTA144W series

### **PACKAGE OUTLINES**

## Plastic single-ended leaded (through hole) package; 3 leads

SOT54



#### Note

mm

5.0

0.48

0.40

0.66

0.55

0.45

0.38

4.8

4.4

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

1.7

1.4

4.2

3.6

2.54

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT54		TO-92	SC-43A		<del>-04-06-28</del> 04-11-16

1.27

14.5

12.7

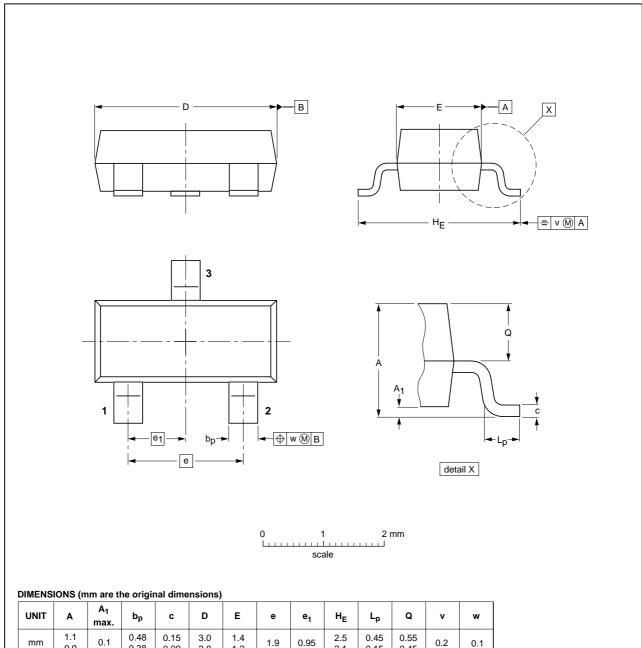
2.5

# PNP resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = 22 k $\Omega$

## PDTA144W series

## Plastic surface-mounted package; 3 leads

SOT23



OUTLINE		REFER	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT23		TO-236AB			<del>-04-11-04-</del> 06-03-16

2004 Aug 05 7

0.38

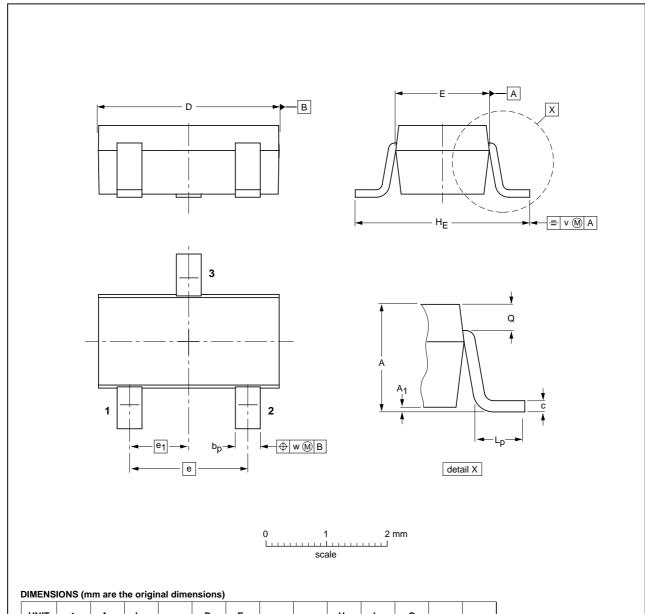
0.9

# PNP resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = 22 k $\Omega$

## PDTA144W series

## Plastic surface-mounted package; 3 leads

**SOT346** 



UNIT	Α	A <sub>1</sub>	bp	С	D	E	е	e <sub>1</sub>	HE	Lp	Q	v	w
mm	1.3 1.0	0.1 0.013	0.50 0.35	0.26 0.10	3.1 2.7	1.7 1.3	1.9	0.95	3.0 2.5	0.6 0.2	0.33 0.23	0.2	0.2

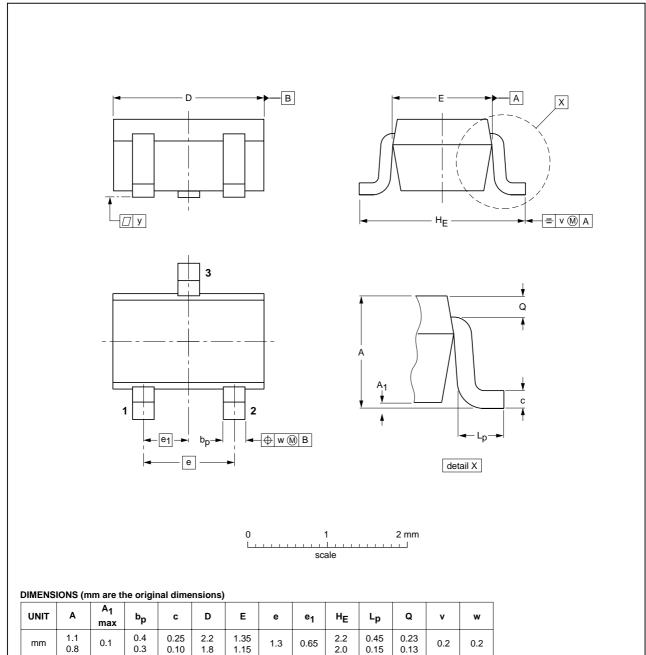
OUTLINE	INE REFERENCES				EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT346		TO-236	SC-59A			<del>04-11-11</del> 06-03-16	

# PNP resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = 22 k $\Omega$

## PDTA144W series

## Plastic surface-mounted package; 3 leads

SOT323



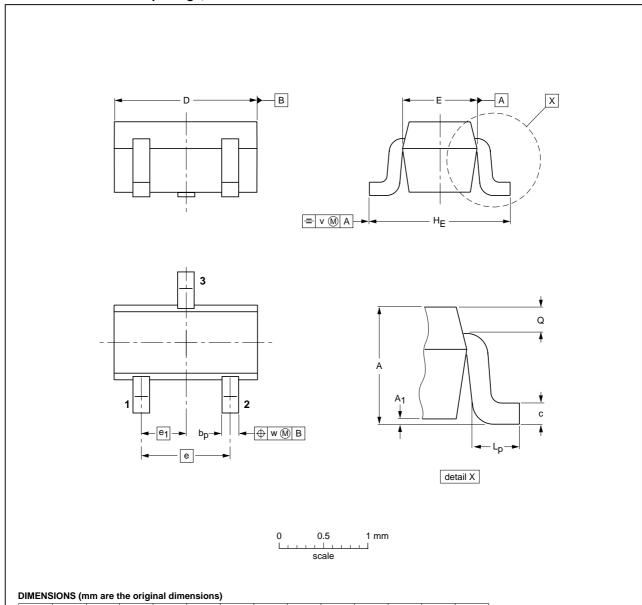
VERSION IEC JEDEC JEITA PROJECTION  SOT323  SC-70  Od-11-04	OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
SO1323   SC-70   +	VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
— \$\psi_{00-03-10}\$	SOT323			SC-70		<del>04-11-04</del> 06-03-16

# PNP resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = 22 k $\Omega$

## PDTA144W series

## Plastic surface-mounted package; 3 leads

SOT416



U	NIT	Α	A <sub>1</sub> max	bp	С	D	E	е	e <sub>1</sub>	HE	Lp	ø	v	w
n	nm	0.95 0.60	0.1	0.30 0.15	0.25 0.10	1.8 1.4	0.9 0.7	1	0.5	1.75 1.45	0.45 0.15	0.23 0.13	0.2	0.2

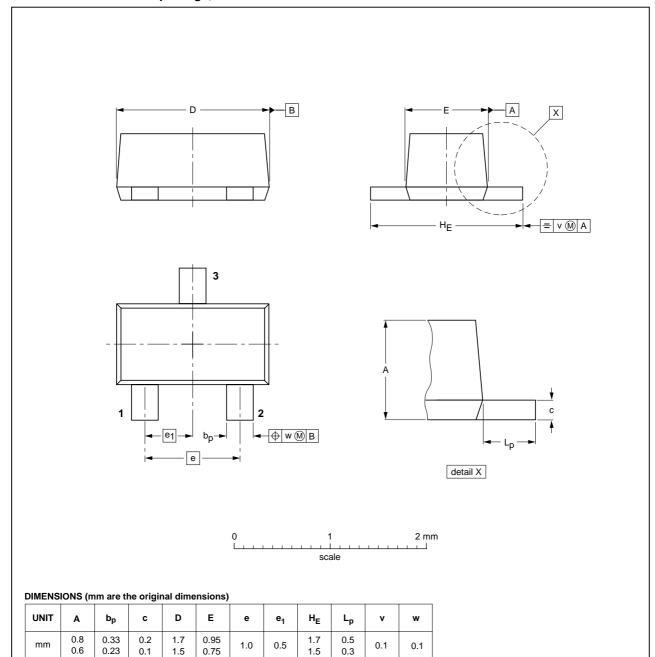
OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	1330E DATE
SOT416			SC-75			<del>04-11-04</del> 06-03-16

# PNP resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = 22 k $\Omega$

## PDTA144W series

## Plastic surface-mounted package; 3 leads

SOT490



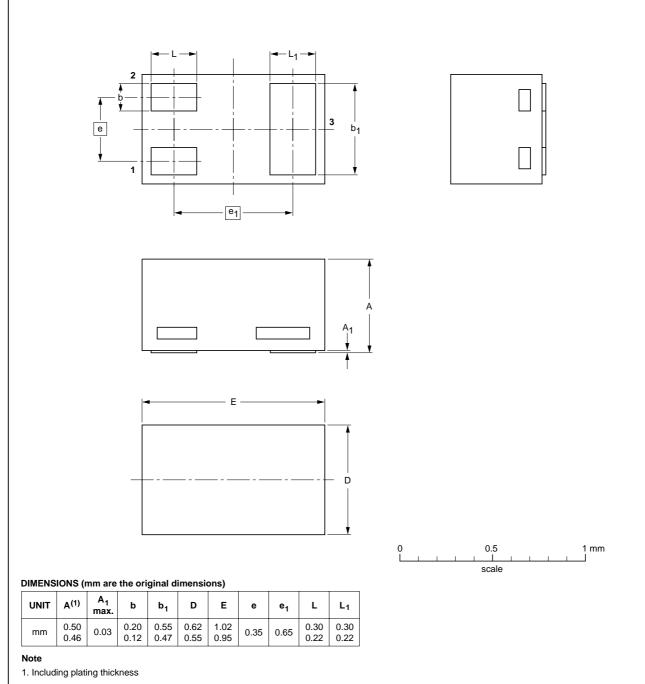
OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT490			SC-89			<del>05-07-28</del> 06-03-16

# PNP resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = 22 k $\Omega$

## PDTA144W series

## Leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.5 mm

**SOT883** 



OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT883			SC-101			<del>03-02-05</del> 03-04-03

## PNP resistor-equipped transistors; R1 = 47 k $\Omega$ , R2 = 22 k $\Omega$

### PDTA144W series

#### **DATA SHEET STATUS**

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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## **NXP Semiconductors**

### **Customer notification**

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

#### **Contact information**

For additional information please visit: http://www.nxp.com
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